

KD2302-VB Datasheet

N-Channel 20 V (D-S) MOSFET

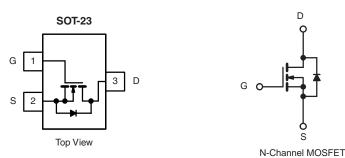
PRODUCT SUMMARY						
V _{DS} (V)	$\mathbf{R}_{DS(on)}$ (Ω) \mathbf{I}_{D} (A) ^e		Q _g (Typ.)			
	0.022 at V _{GS} = 4.5 V	6 ^a				
20	0.028 at V _{GS} = 2.5 V	6 ^a	8.8 nC			
	0.039 at V _{GS} = 1.8 V	5.6				

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- Trench Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- DC/DC Converters
- Load Switch for Portable Applications



Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage		V _{GS}	± 12	V	
	T _C = 25 °C		6 ^a		
Continuous Drain Current (T 150 °C)	T _C = 70 °C		5.1		
Continuous Drain Current ($T_J = 150 \ ^{\circ}C$)	T _A = 25 °C		5 ^{b, c}		
	T _A = 70 °C		4 ^{b, c}	A	
Pulsed Drain Current		I _{DM}	20		
	T _C = 25 °C		1.75		
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	1.04 ^{b, c}		
	T _C = 25 °C		2.1		
Maximum Dawar Dissinction	T _C = 70 °C		1.3	w	
Maximum Power Dissipation	T _A = 25 °C	P _D	1.25 ^{b, c}	vv	
	T _A = 70 °C	1	0.8 ^{b, c}		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	
Soldering Recommendations (Peak Temperature)			260		

THERMAL RESISTANCE RATINGS								
Parameter		Symbol	Typical	Maximum	Unit			
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	80	100	°C/W			
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	40	60	0/11			

Notes:

a. Package limited

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. Maximum under steady state conditions is 125 $^{\circ}\text{C/W}.$

e. Based on T_C = 25 °C.





SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
		-	1	1	-		
	$V_{GS} = 0 V, I_D = 250 \mu A$	20			V		
	I _р = 250 цА		25		- mV/°		
			- 2.6				
V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	0.45		1.0	V		
I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 8 V$			± 100	nA		
le e e	$V_{DS} = 20 V, V_{GS} = 0 V$			1	μA		
'DSS	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			10			
I _{D(on)}	$V_{DS}{\leq}5$ V, V_{GS} = 4.5 V	20			A		
	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 5.0 \text{ A}$		0.022				
R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 4.7 \text{ A}$		0.028		Ω		
	$V_{GS} = 1.8 \text{ V}, \text{ I}_{D} = 4.3 \text{ A}$		0.039				
9 _{fs}	V _{DS} = 10 V, I _D = 5.0 A		24		S		
				<u> </u>	I		
ynamic ^b Iput Capacitance C _{iss}			865		[
	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz				pF		
			-				
	$V_{DS} = 10 \text{ V}. \text{ V}_{CS} = 5 \text{ V}. \text{ I}_{D} = 5.0 \text{ A}$		-	18			
Qg					nC		
Q _{as}	$V_{DS} = 10 V_{c} V_{CS} = 4.5 V_{c} I_{D} = 5.0 A_{c}$		-				
			-				
_	f = 1 MHz	0.5		4.8	Ω		
			8	16			
	$V_{DD} = 10 \text{ V}, \text{ R}_{1} = 2.2 \Omega$		-	-	-		
	$I_D \cong 4 \text{ A}, \text{ V}_{\text{GEN}} = 4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$			-			
			-		_		
			-	-	ns		
	$V_{DD} = 10 \text{ V}, \text{ R}_1 = 2.2 \Omega$		-	-			
	$I_D \cong 4 \text{ A}, V_{\text{GEN}} = 5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	-			
	č		-				
		L	0	12	L		
	T _C = 25 °C			1.75			
	0				A		
	$l_{e} = 4 A$, $V_{ee} = 0 V$		0.75		V		
			-		ns		
					nC		
	$I_F = 4 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^\circ\text{C}$		7	10	10		
everse Recovery Fall Time t _a everse Recovery Rise Time t _b		1	1 /	1	1		
	Symbol V_{DS} $\Delta V_{DS}/T_J$ $\Delta V_{GS(th)}/T_J$ $\Delta V_{GS(th)}/T_J$ I_{GSS} I_{DSS} $I_{D(on)}$ $R_{DS(on)}$ G_{iss} C_{iss} C_{oss} C_{rss} Q_{gd} R_g $L_d(on)$ t_r $t_d(on)$ t_f $t_d(on)$ t_r I_{SM} V_{SD}	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A \\ \hline \Delta V_{GS(th)}/T_J & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A \\ \hline V_{CS(th)} & V_{DS} = 0 \ V, \ V_{GS} = \pm 8 \ V \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ V_{DS} = 20 \ V, \ V_{GS} = 0 \ V, \ T_J = 70 \ ^{\circ}C \\ \hline I_{D(on)} & V_{DS} \le 5 \ V, \ I_D = 5.0 \ A \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline V_{GS} = 1.8 \ V, \ I_D = 5.0 \ A \\ \hline V_{GS} = 1.8 \ V, \ I_D = 5.0 \ A \\ \hline V_{DS} = 10 \ V, \ V_{GS} = 0 \ V, \ f = 1 \ MHz \\ \hline C_{rss} & V_{DS} = 10 \ V, \ V_{GS} = 5 \ V, \ I_D = 5.0 \ A \\ \hline \hline U_{C} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline U_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline U_{D} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline U_{D} = 4 \ A, \ V_{GEN} = 4.5 \ V, \ I_D = 5.0 \ A \\ \hline \hline U_{D} = 4 \ A, \ V_{GEN} = 4.5 \ V, \ I_D = 1 \ \Omega \\ \hline I_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline U_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline U_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline U_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline V_{SD} \ I_S = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega \\ \hline \hline V_{SD} \ I_S = 4 \ A, \ V_{GS} = 0 \ V \\ \hline \hline V_{Tr} \ I_E = 4 \ A, \ U/dt = 100 \ A/\mu_S, \ T_1 = 25 \ ^{\circ}C \\ \hline \hline V_{SD} \ V_{SD} \ I_S = 4 \ A, \ U/dt = 100 \ A/\mu_S, \ T_1 = 25 \ ^{\circ}C \\ \hline \hline \hline V_{Tr} \ V_{SD} \ V$	$\begin{tabular}{ c c c c } \hline Symbol & Test Conditions & Min. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 20 \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A & 0.45 \\ \hline \Delta V_{GS(th)}/T_J & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 0.45 \\ \hline V_{GS(th)}/T_J & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 0.45 \\ \hline V_{GS(th)} & V_{DS} = 0 \ V, \ V_{GS} = 0 \ V & V_{GS} = 18 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & V_{DS} = 10 \ V, \ V_{DS} = 5 \ V, \ I_D = 5.0 \ A & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & V_{DS} = 10 \ V, \ V_{DS} = 10 \ V \ V_{DS} = 10 \ V, \ V_{DS} = 10 \ V \ V_{DS} = 10 \ V \ V_{DS} = 10 \ $	$ \begin{array}{ c c c c c c } \hline Symbol & Test Conditions & Min. Typ. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 20 & 25 \\ \hline & \Delta V_{GS}(m) & I_D = 250 \ \mu A & 0.45 & -2.6 \\ \hline V_{GS}(m) & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 0.45 & -2.6 \\ \hline V_{GS}(m) & V_{DS} = 0 \ V, \ V_{GS} = 4 \ V & 0.45 & -2.6 \\ \hline V_{GS}(m) & V_{DS} = 0 \ V, \ V_{GS} = 0 \ V & V_{GS} = 0 \ V & 0.5 & -2.6 \\ \hline V_{DS} & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & 0.5 & -2.6 \\ \hline V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 0 \ V & V_{DS} = 20 \ V, \ V_{GS} = 25 \ V, \ I_D = 5.0 \ A & 0.022 \\ \hline V_{DS} = 10 \ V, \ V_{GS} = 10 \ V, \ I_D = 5.0 \ A & 0.039 \\ \hline g_{fS} & V_{DS} = 10 \ V, \ V_{GS} = 0 \ V, \ f = 1 \ MHz & 105 \\ \hline C_{rss} & V_{DS} = 10 \ V, \ V_{GS} = 5 \ V, \ I_D = 5.0 \ A & 12 \\ \hline 0.7 \ R_g & f = 10 \ V, \ V_{GS} = 5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_D = 5.0 \ A & 11.1 \\ \hline M_{D} = 4 \ A, \ V_{GEN} = 4.5 \ V, \ R_g = 1 \ \Omega & 31 \\ \hline I_{L} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega & 31 \\ \hline I_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega & 31 \\ \hline M_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega & 31 \\ \hline M_{C} = 10 \ V, \ R_L = 2.2 \ \Omega & 31 \\ \hline M_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega & 31 \\ \hline M_{C} = 113 \ I_{D} = 4 \ A, \ V_{GEN} = 5 \ V, \ R_g = 1 \ \Omega & 31 \\ \hline M_{C} = 12 \ M_{C} & M_{C} = 113 \\ \hline M_{C} = 12 \ M_{C} & M_{C} = 112 \\ \hline M_{C} = 12 \ M_{C} & M_{C} = 112 \ M_{C} & M_{C} = 12 \ M_{C} & M_{C} = 112 \\ \hline M_{C} = 12 \ M_{C} & M_{C} = 12 \ M_{C$	$\begin{tabular}{ c c c c c } \hline Symbol & Test Conditions & Min. Typ. Max. \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 20 & 25 & 26 & 26 & 26 & 26 & 26 & 26 & 26$		

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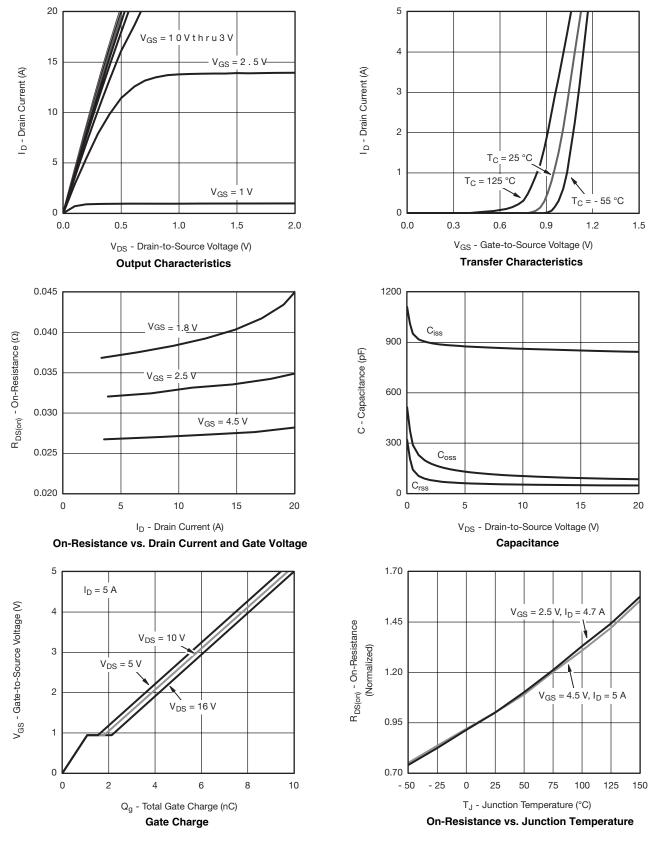
Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 % b. Guaranteed by design, not subject to production testing.

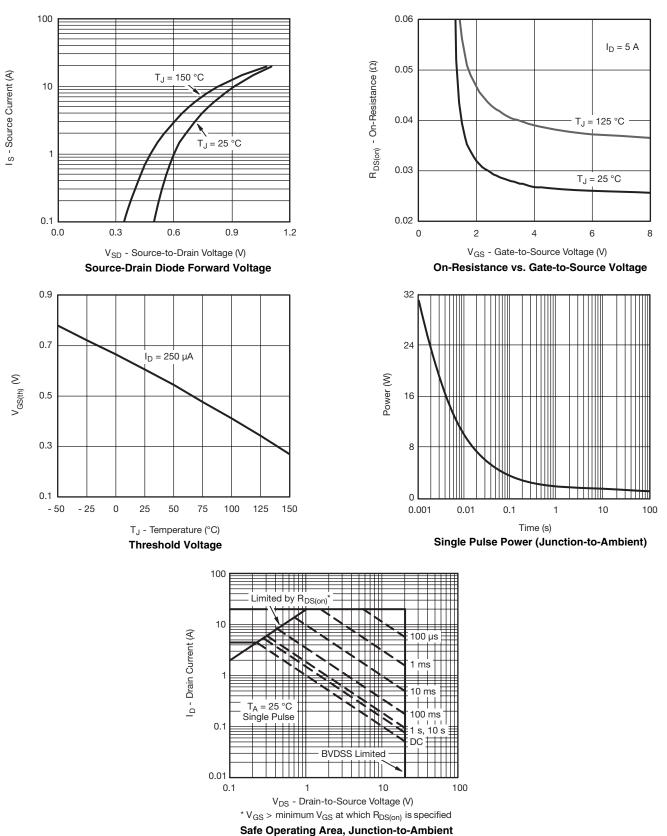
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







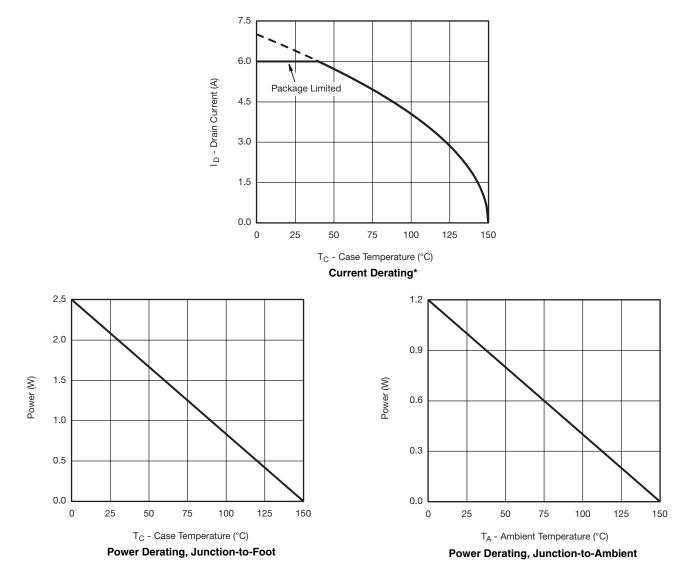




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



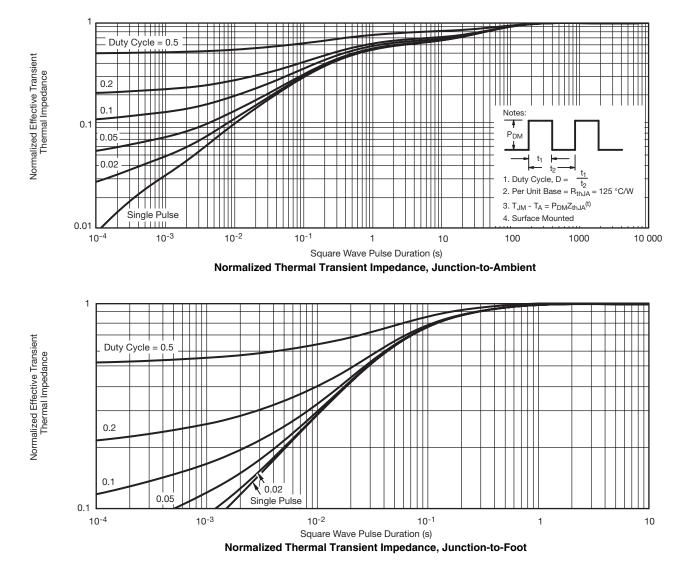
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max.)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

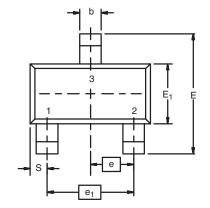


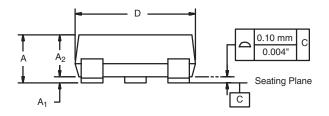
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





SOT-23 (TO-236): 3-LEAD







Dim	MILLI	METERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.6	4 Ref	0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K, 09- DWG: 5479	Jul-01				



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)



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